

High Efficiency Standard Rectifier

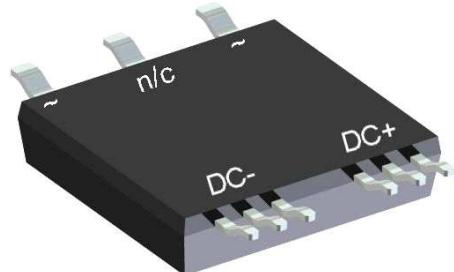
1~ Rectifier
$V_{RRM} = 1200 \text{ V}$
$I_{DAV} = 124 \text{ A}$
$I_{FSM} = 400 \text{ A}$

1~ Rectifier Bridge

Part number

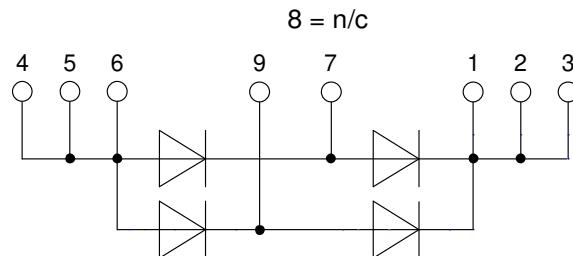
DLA100B1200LB

Marking on Product: *DLA100B1200LB*



Backside: isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode Bridge for main rectification

Package: SMPD

- Isolation Voltage: 3000 V~
- Industry convenient outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

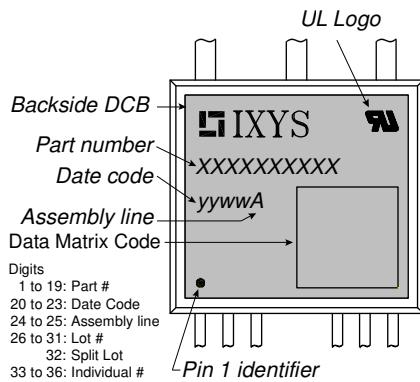
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Rectifier

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			1200	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			1200	V
I_R	reverse current	$V_R = 1200 \text{ V}$ $V_R = 1200 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 150^\circ C$		10 0.1	μA mA
V_F	forward voltage drop	$I_F = 50 \text{ A}$	$T_{VJ} = 25^\circ C$		1.23	V
		$I_F = 100 \text{ A}$			1.45	V
		$I_F = 50 \text{ A}$	$T_{VJ} = 150^\circ C$		1.15	V
		$I_F = 100 \text{ A}$			1.44	V
I_{DAV}	bridge output current	$T_C = 135^\circ C$ 180° sine	$T_{VJ} = 175^\circ C$		124	A
V_{F0} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ C$		0.75 4.2	V $m\Omega$
					1	K/W
R_{thJC}	thermal resistance junction to case					
R_{thCH}	thermal resistance case to heatsink			0.40		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ C$		150	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		400	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		430	A
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ C$		340	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		365	A
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		800	A^2s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		770	A^2s
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ C$		580	A^2s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		555	A^2s
C_J	junction capacitance	$V_R = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	13		pF

Package SMPD			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			100	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				8.5		g
F_c	mounting force with clip		40		130	N
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	1.6			mm
$d_{Spb/Apb}$		terminal to backside	4.0			mm
V_{ISOL}	isolation voltage	$t = 1$ second $t = 1$ minute	3000 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	2500		V



Part description

D = Diode
 L = Low Voltage Standard Rectifier
 A = (up to 1200V)
 100 = Current Rating [A]
 B = 1~ Rectifier Bridge
 1200 = Reverse Voltage [V]
 LB = SMPD-B

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DLA100B1200LB-TUB	DLA100B1200LB	Tube	20	517180
Alternative	DLA100B1200LB-TRR	DLA100B1200LB	Tape & Reel	200	517187

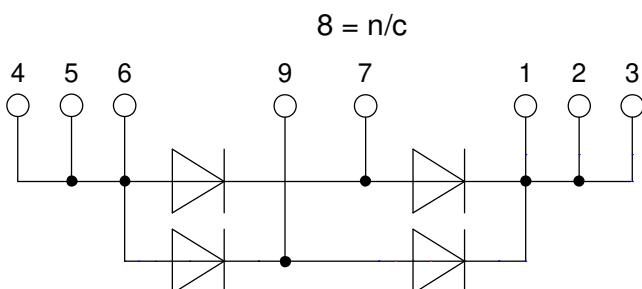
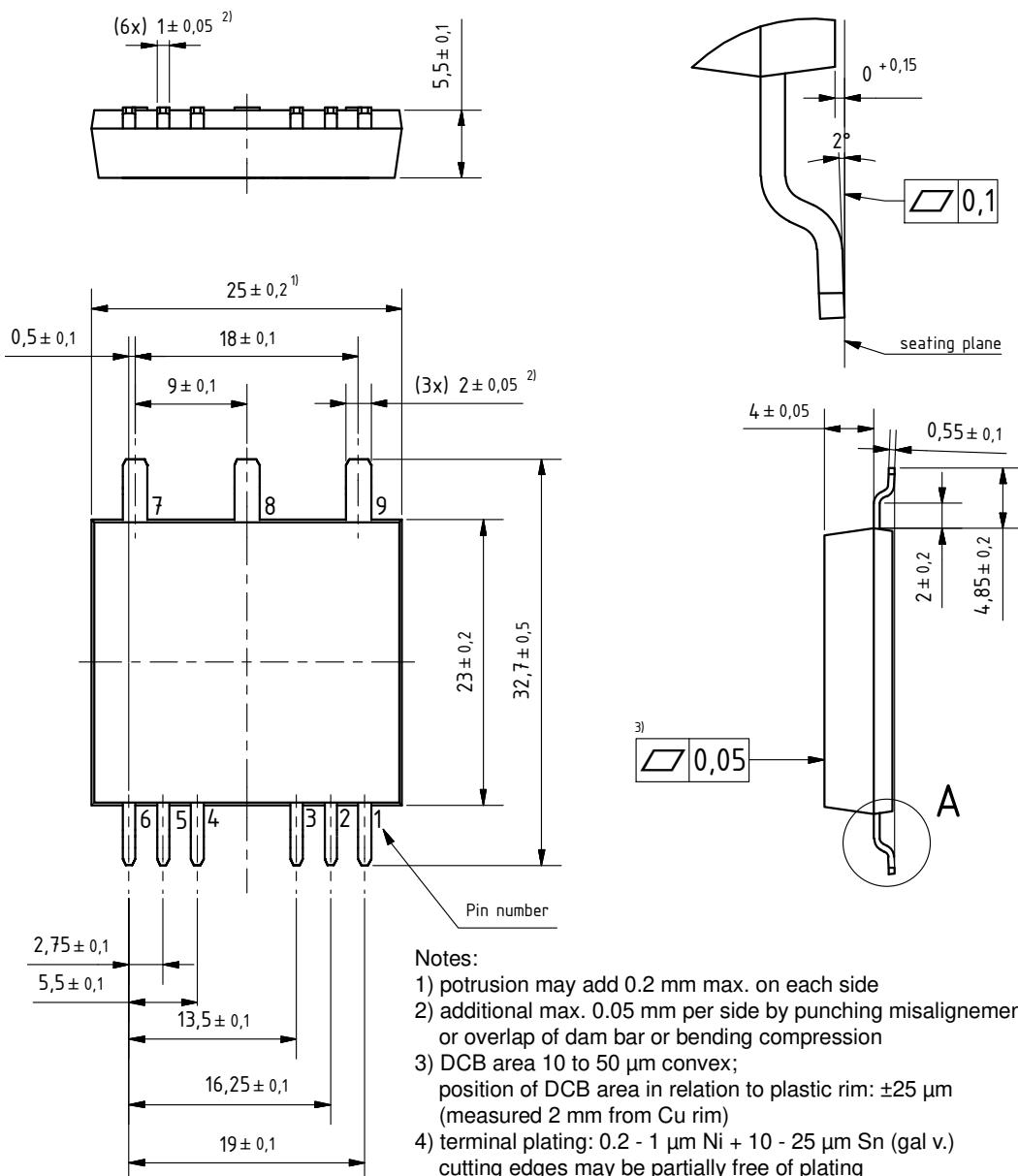
Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175$ °C

	Rectifier
$V_{0\ max}$	threshold voltage
$R_{0\ max}$	slope resistance *

V
 $m\Omega$

Outlines SMPD
A (8 : 1)


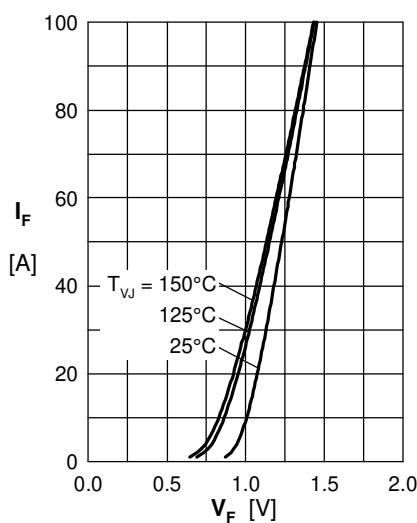
Rectifier


Fig. 1 Forward current versus voltage drop per diode

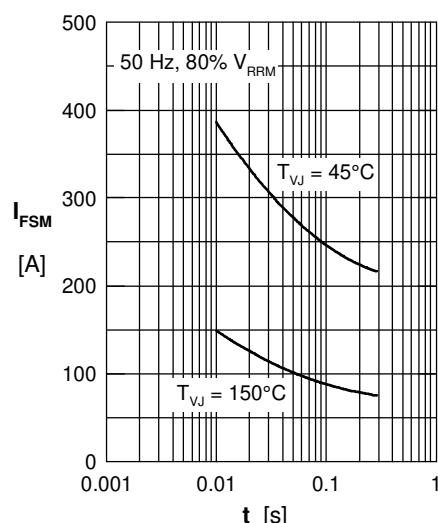


Fig. 2 Surge overload current

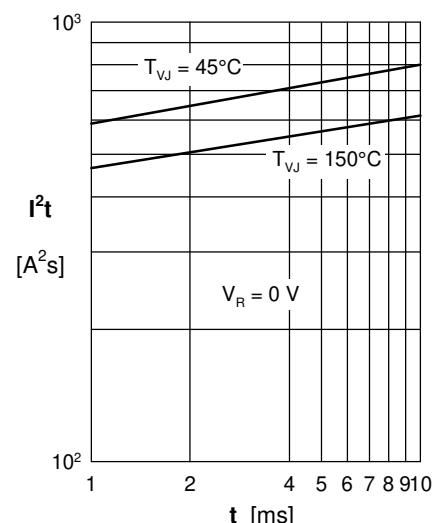


Fig. 3 I^2t versus time per diode

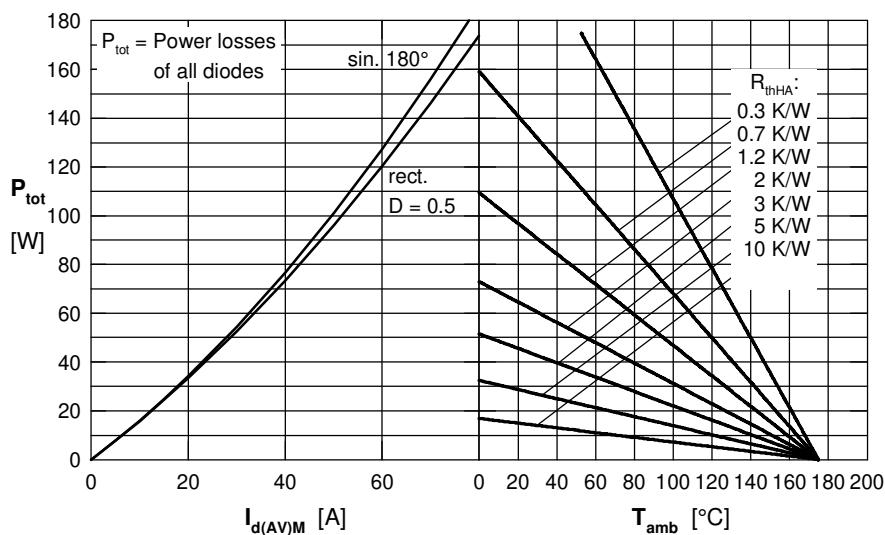


Fig. 4 Power dissipation vs. bridge output current and ambient temperature

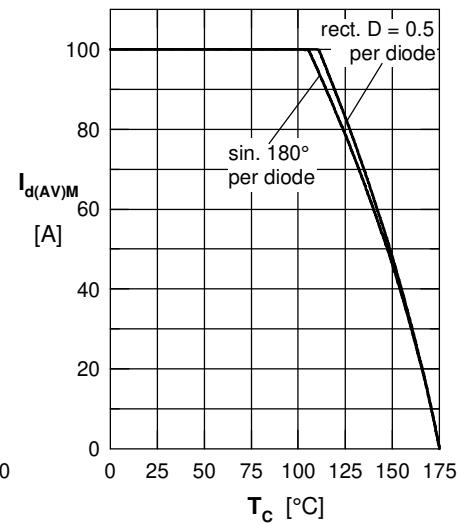


Fig. 5 Max. bridge output current vs. case temperature

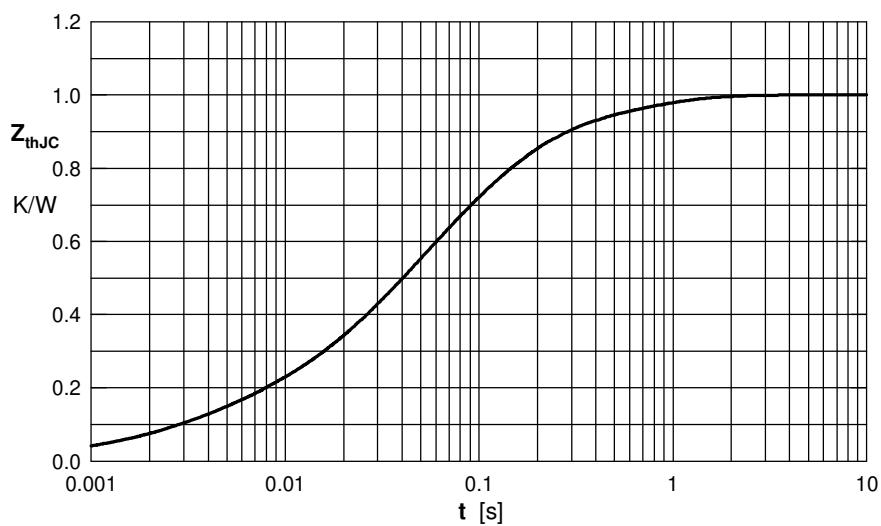


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.09	0.003
2	0.116	0.062
3	0.386	0.1
4	0.128	0.55

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